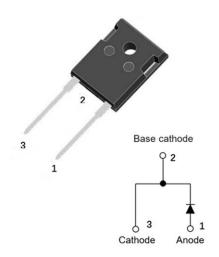






Silicon Carbide Schottky Diode

V_{RRM}	650V
I _{F (123°C)}	50A
Q _C	136nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

• Package: TO-247AC

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D106550NYG5
Reverse voltage (Repetitive peak) @ T _j =25°C	V_{RRM}	٧	650
Reverse voltage (Surge peak) @ T _j =25°C	V_{RSM}	٧	650
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	650
Continuous forward current @ T _C =25°C			93
Continuous forward current @ T _C =110°C	I _F	А	57
Continuous forward current @ T _C =123°C			50
Non-repetitive peak forward surge current @ T _C =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	380
Power Dissipation@ T _C =25°C		W	288
Power Dissipation@ T _C =110°C	P _{TOT}		125
i²t Value@ T _C =25°C ,tp=10ms	∫ i²dt	A ² S	722
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175

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■Electrical Characteristics (Ta=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage	V _F	>	I _F =50A, T _j =25°C	1.45	1.70
			I _F =50A, T _j =175°C	2.0	-
Reverse current	I _R	μА	V _R =650V, T _j =25°C	1	25
			V _R =650V, T _j =175°C	20	-
Total capacitive charge	Q _C	nC	V_R =400V, T_j =25°C , Q_C = $\int_0^{VR} C(V) dV$	136	-
Total capacitance	С	pF	V _R =0V, f=1MHZ	2530	-
			V _R =200V, f=1MHZ	250	-
			V _R =400V, f=1MHZ	245	-
Capacitance stored energy	Ec	μJ	V _R =400V	21	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R _{eJ-C}	°C W	0.52

■Typical Characteristics (Typical)

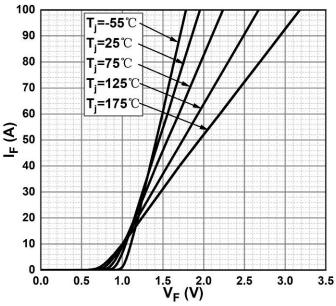


Figure 1. Forward Characteristics

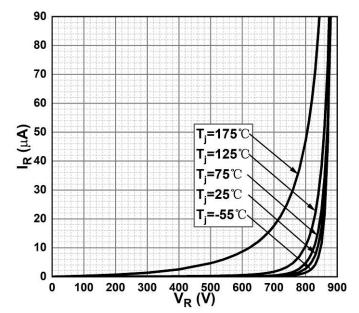
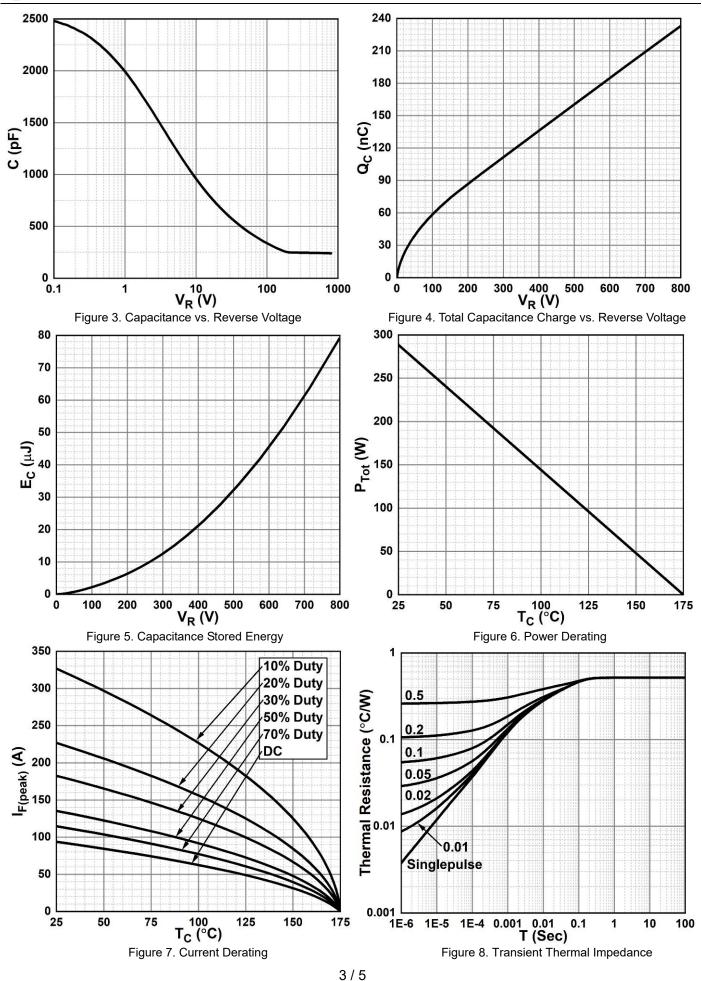


Figure 2. Reverse Characteristics

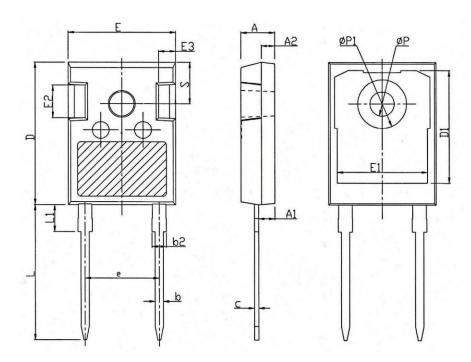
YJD106550NYG5





■Outline Dimensions

TO-247AC



TO-247AC				
Dim	Min	Max		
Α	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
Е	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
φР	3.40	3.80		
φP1	-	7.30		
S	6.15BSC			

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